

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China









TYNx10 Series

STANDARD 10A SCR

Table 1: Main Features

| Symbol | Value | Unit | |
|------------------------------------|------------------|------|--|
| I _{T(RMS)} | 10 | Α | |
| V _{DRM} /V _{RRM} | 400, 600 and 800 | V | |
| I _{GT} | 15 | mA | |

DESCRIPTION

The **TYNx10** Silicon Controlled Rectifiers is a high performance glass passivated technology.

This general purpose Silicon Controlled Rectifiers is designed for power supply up to 400Hz on resistive or inductive load.

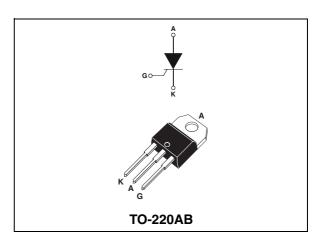


Table 2: Order Codes

| Part Numbers | Marking |
|--------------|---------|
| TYN410RG | TYN410 |
| TYN610RG | TYN610 |
| TYN810RG | TYN810 |

Table 3: Absolute Ratings (limiting values)

| Symbol | Parameter | | | Value | Unit |
|---------------------|--|--------------------------|------------------------|---------------|---------|
| I _{T(RMS)} | RMS on-state current (180° conduction angle) $T_c = 100$ °C | | 10 | Α | |
| IT _(AV) | Average on-state current (180° conducti | on angle) | T _c = 100°C | 6.4 | Α |
| l=0 | Non repetitive surge peak on-state | $t_{p} = 8.3 \text{ ms}$ | T _i = 25°C | 105 | Α |
| I _{TSM} | current | $t_p = 10 \text{ ms}$ | 1, - 23 0 | 100 | |
| l²t | I ² t Value for fusing | $t_p = 10 \text{ ms}$ | T _j = 25°C | 50 | A^2 s |
| dl/dt | Critical rate of rise of on-state current $I_G = 100 \text{ mA}$, $dI_G/dt = 0.1 \text{ A/}\mu\text{s}$ | | T _j = 125°C | 50 | A/µs |
| I _{GM} | Peak gate current $t_p = 20 \mu s$ | | T _j = 125°C | 4 | Α |
| $P_{G(AV)}$ | Average gate power dissipation | | T _j = 125°C | 1 | W |
| P_{GM} | Maximum gate power $t_p = 20 \mu s$ | | T _j = 125°C | 10 | W |
| V_{DRM} | TYN410 | | | 400 | |
| V _{DRM} | Repetitive peak off-state voltage | TYN610 | T _j = 125°C | 600 | V |
| * KKIVI | RRM | | | 800 | |
| T _{stg} | Storage junction temperature range | | | - 40 to + 150 | °C |
| T_j | Operating junction temperature range | | | - 40 to + 125 | O |
| TL | Maximum lead temperature for soldering during 10s at 2mm from case | | | 260 | °C |

Tables 4: Electrical Characteristics ($T_j = 25$ °C, unless otherwise specified)

| Symbol | Test Conditions | | | Value | Unit |
|------------------|--|------------------------|----------|-------|------|
| I _{GT} | $-V_D = 12 \text{ V (D.C.)}$ $R_L = 33 \Omega$ | | MAX. | 15 | mA |
| V _{GT} | | | MAX. | 1.5 | V |
| V _{GD} | $V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $T_j = 110^{\circ}\text{C}$ | | MIN. | 0.2 | V |
| t _{gt} | $V_D = V_{DRM}$ $I_G = 40$ mA $dI_G/dt = 0.5$ A/ μ s | | TYP. | 2 | μs |
| I _H | I _T = 100 mA Gate open | | MAX. | 30 | mA |
| ΙL | $I_G = 1.2 \times I_{GT}$ | | TYP. | 50 | mA |
| dV/dt | Linear slope up to: $V_D = 67 \% V_{DRM}$ Gate open $T_j = 110 ^{\circ}C$ | | MIN. | 200 | V/µs |
| V _{TM} | I _{TM} = 20 A tp = 380 μs | | MAX. | 1.6 | V |
| I _{DRM} | $V_{DRM} = V_{RRM}$ | T _j = 25°C | MAX. | 10 | μΑ |
| I _{RRM} | *DHM = *HHM | T _j = 110°C | IVI/A/A. | 2 | mA |
| t _q | $V_D = 67 \% V_{DRM}$ $I_{TM} = 20 A$ $V_R = 25 V$ $dI_{TM}/dt = 30 A/\mu s$ $dV_D/dt = 50 V/\mu s$ $T_j = 110 ^{\circ} C$ | | TYP. | 70 | μs |

Table 5: Thermal Resistance

| Symbol | Parameter | | Unit |
|----------------------|-------------------------|-----|------|
| R _{th(j-c)} | Junction to case (D.C.) | 2.5 | °C/W |
| R _{th(j-a)} | Junction to ambient | 60 | °C/W |

Figure 1: Maximum average power dissipation versus average on-state current

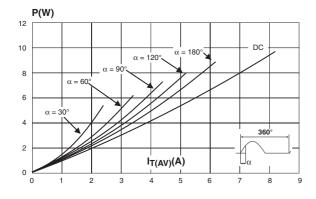
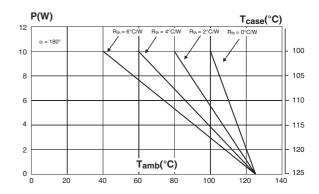


Figure 2: Correlation between maximum average power dissipation and maximum allowable temperature (T_{amb} and T_{lead})



2/6

Figure 3: Average on-state current versus case temperature

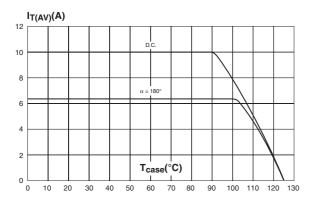


Figure 5: Relative variation of gate trigger current versus junction temperature

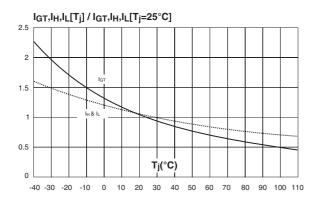


Figure 7: Non-repetitive surge peak on-state current for a sinusoidal pulse with width tp < 10 ms, and corresponding values of l^2t

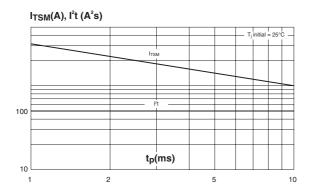


Figure 4: Relative variation of thermal impedance versus pulse duration

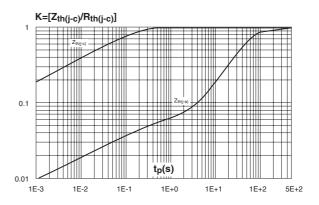


Figure 6: Surge peak on-state current versus number of cycles

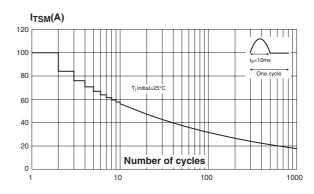
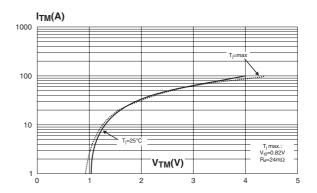


Figure 8: On-state characteristics (maximum values)



577

Figure 9: Ordering Information Scheme

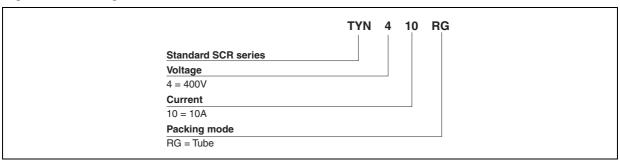


Table 6: Product Selector

| Part Numbers | | Voltage (xxx) | | Sensitivity Package | | |
|--------------|-------|---------------|------|---------------------|----------|--|
| Fait Numbers | 400 V | 600 V | 800V | Sensitivity | Fackage | |
| TYN410RG | Х | | | | | |
| TYN610RG | | Х | | 15 mA | TO-220AB | |
| TYN810RG | | | Х | | | |

4/6

DIMENSIONS REF. Millimeters Inches Тур. Min. Тур. Max. Min. Max. В Α 15.20 15.90 0.598 0.625 Ø١ a1 3.75 0.147 13.00 14.00 0.511 a2 0.551 L В 10.00 10.40 0.393 0.409 0.034 b1 0.61 0.88 0.024 b2 1.23 1.32 0.048 0.051 14 С 4.40 4.60 0.173 0.181 13 0.49 0.70 0.019 0.027 c1 a1 c2 2.72 0.094 0.107 c2 2.40 2.40 2.70 0.094 0.106 е 6.20 0.259 6.60 0.244 ØΙ 3.75 0.147 3.85 0.151 15.80 16.40 16.80 0.622 14 0.646 0.661 2.95 L 2.65 0.104 0.116 12 1.14 1.70 0.044 0.066 13 1.14 1.70 0.044 0.066 M 2.60 0.102

Figure 10: TO-220AB Package Mechanical Data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

Table 7: Ordering Information

| Ordering type | Marking | Package | Weight | Base qty | Delivery mode |
|---------------|---------|----------|--------|----------|---------------|
| TYN410RG | TYN410 | | | | |
| TYN610RG | TYN610 | TO-220AB | 2.3 g | 50 | Tube |
| TYN810RG | TYN810 | 1 | | | |

Table 8: Revision History

| Date | Revision | Description of Changes |
|-------------|----------|--|
| Sep-2001 | 1A | First issue. |
| 13-Feb-2006 | 2 | TO-220AB delivery mode changed from bulk to tube. ECOPACK statement added. |

Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners

© 2006 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America www.st.com

